

REVISIONS

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STANDARDIZED MILITARY DRAWING THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE AMSC N/A	PREPARED BY <i>Joseph A. Kirby</i>	DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		
	CHECKED BY <i>Charles E. Benson</i>	MICROCIRCUIT, LINEAR, 12-BIT D/A CONVERTER, MONOLITHIC SILICON		
	APPROVED BY <i>[Signature]</i>	SIZE A	CAGE CODE 67268	5962-91652
	DRAWING APPROVAL DATE 91-09-20	SHEET 1 OF 17		
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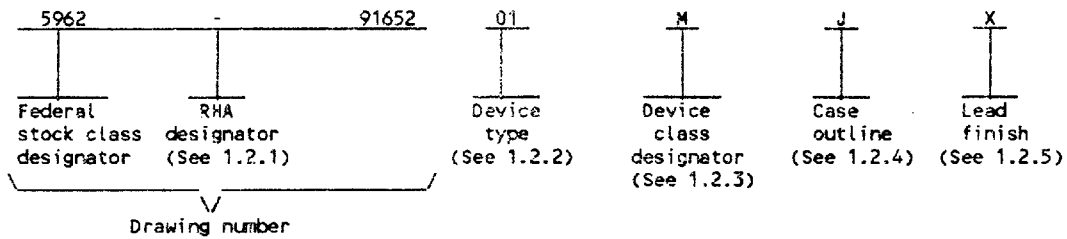
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1. SCOPE

1.1 Scope. This drawing forms a part of a one part - one part number documentation system (see 6.6 herein). Two product assurance classes consisting of military high reliability (device classes B, Q, and M) and space application (device classes S and V), and a choice of case outlines and lead finishes are available and are reflected in the Part or Identifying Number (PIN). Device class M microcircuits represent non-JAM class B microcircuits in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAM devices". When available, a choice of radiation hardness assurance (RHA) levels are reflected in the PIN.

1.2 PIN. The PIN shall be as shown in the following example:



1.2.1 Radiation hardness assurance (RHA) designator. Device classes M, B, and S RHA marked devices shall meet the MIL-M-38510 specified RHA levels and shall be marked with the appropriate RHA designator. Device classes Q and V RHA marked devices shall meet the MIL-I-38535 specified RHA levels and shall be marked with the appropriate RHA designator. A dash (-) indicates a non-RHA device.

1.2.2 Device type(s). The device type(s) shall identify the circuit function as follows:

Device type	Generic number	Circuit function
01	TDC1112-1	12-Bit D/A Converter, .048% E _{LD}
02	TDC1112-2	12-Bit D/A Converter, .024% E _{LD}

1.2.3 Device class designator. The device class designator shall be a single letter identifying the product assurance level as follows:

Device class	Device requirements documentation
M	Vendor self-certification to the requirements for non-JAM class B microcircuits in accordance with 1.2.1 of MIL-STD-883
B or S	Certification and qualification to MIL-M-38510
Q or V	Certification and qualification to MIL-I-38535

1.2.4 Case outline(s). For device classes M, B, and S, case outline(s) shall meet the requirements in appendix C of MIL-M-38510 and as listed below. For device classes Q and V, case outline(s) shall meet the requirements of MIL-I-38535, appendix C of MIL-M-38510, and as listed below.

Outline letter	Case outline
J	D-3 (24-lead, 1.290" x .610" x .225") Dual-In-Line
3	C-4 (28-terminal, .460" x .460" x .100"), square chip carrier package.

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1.2.5 Lead finish. The lead finish shall be as specified in MIL-M-38510 for classes M, B, and S or MIL-I-38535 for classes Q and V. Finish letter "X" shall not be marked on the microcircuit or its packaging. The "X" designation is for use in specifications when lead finishes A, B, and C are considered acceptable and interchangeable without preference.

1.3 Absolute maximum ratings 1/

Supply Voltages:	
V _{EEA} (measured to A _{GND})	-7.0 V to +0.5 V
V _{EEA} (measured to D _{GND})	-50 mV to +50 mV
V _{EEA} (measured to J _{GND})	-7.0 V to +0.5 V
V _{EED} (measured to D _{GND})	-0.5 V to +0.5 V
Inputs:	
CONV, CONV, FT, D ₁₂ (measured to D _{GND}) 2/	V _{EED} to +0.0 V
REF+, REF-, applied voltage (measured to A _{GND}) 2/	V _{EEA} to +0.0 V
REF+, REF-, applied current, externally forced 3/ 4/	±5 mA
Digital input current, externally forced 3/ 4/	±3 mA
Outputs:	
OUT+, OUT-, applied voltage (measured to A _{GND}) 2/	-2.0 V to +2.0 V
OUT+, OUT-, applied current externally forced, (measured to D _{GND}) 2/ 4/	50 mA
Short-circuit duration (single output to GND)	Unlimited
Storage temperature range	-60°C to +150°C
Junction temperature (T _J)	+200°C
Lead temperature (soldering, 10 seconds)	+300°C
Power dissipation (P _D)	1.6 W
Thermal resistance, junction-to-case (θ _{JC})	See MIL-M-38510, appendix C

1/ Absolute maximum ratings are limiting values applied individually while all other parameters are within specified operating conditions. Functional operation under any of these conditions is not implied. Device performance and reliability are guaranteed only if the operating conditions are not exceeded.

2/ Applied voltage must be current limited to specified range.

3/ Forcing voltage must be limited to specified range

4/ Current is specified as conventional current flowing into the device.

1.4 Recommended operating conditions

Clock frequency (f _{CLK})	0 Hz to 50 MHz
Analog supply voltage (V _{EEA}) (measured to A _{GND})	-4.9 V to -5.5 V
Analog supply voltage (V _{EEA}) (measured to V _{EED})	-20 mV to +20 mV
Digital supply voltage (V _{EED}) (measured to D _{GND})	-4.9 V to -5.5 V
Analog ground voltage (V _{AGND}) (measured to D _{GND})	-0.1 V to +0.1 V
Reference voltage range (measured at REF-)	-0.7 V to -1.3 V
Reference current range (measured at REF+)	0.575 mA to 0.675 mA
Compensation capacitor (C _c)	0.01 μF minimum
Digital input voltage, logic LOW (V _{IL})	-1.6 V maximum
Digital input voltage, logic HIGH (V _{IH})	-1.0 V minimum
Input data setup time (t _S)	18 ns minimum
Input data hold time (t _H)	0 ns minimum
Setup time, data to FT (t _{SE})	7 ns maximum
Hold time, data to FT (t _{HE})	24 ns maximum
CONV input voltage, common mode range (V _{ICM})	-0.5 V to -2.0 V
CONV input voltage, differential (V _{IDF})	0.4 V to 1.2 V
CONV pulse width, low (t _{PVL}):	
≥ 40 MSPS	10.5 ns minimum
< 40 MSPS	11 ns minimum
CONV pulse width, high (t _{PWH}):	
≥ 40 MSPS	8.5 ns minimum
< 40 MSPS	9.0 ns minimum
Case operating temperature range (T _C)	-55°C to +125°C

**STANDARDIZED
MILITARY DRAWING**

DEFENSE ELECTRONICS SUPPLY CENTER
DAYTON, OHIO 45444

SIZE
A

5962-91652

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2. APPLICABLE DOCUMENTS

2.1 Government specifications, standards, bulletin, and handbook. Unless otherwise specified, the following specifications, standards, bulletin, and handbook of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

SPECIFICATIONS

MILITARY

- MIL-M-38510 - Microcircuits, General Specification for.
- MIL-I-38535 - Integrated Circuits, Manufacturing, General Specification for.

STANDARDS

MILITARY

- MIL-STD-480 - Configuration Control-Engineering Changes, Deviations and Waivers.
- MIL-STD-883 - Test Methods and Procedures for Microelectronics.

BULLETIN

MILITARY

- MIL-BUL-103 - List of Standardized Military Drawings (SMD's).

HANDBOOK

MILITARY

- MIL-HDBK-780 - Standardized Military Drawings.

(Copies of the specifications, standards, bulletin, and handbook required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.

3. REQUIREMENTS

3.1 Item requirements. The individual item requirements for device class M shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein. The individual item requirements for device classes B and S shall be in accordance with MIL-M-38510 and as specified herein. For device classes B and S, a full electrical characterization table for each device type shall be included in this SMD. The individual item requirements for device classes Q and V shall be in accordance with MIL-I-38535, the device manufacturer's Quality Management (QM) plan, and as specified herein.

3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-M-38510 for device classes M, B, and S and MIL-I-38535 for device classes Q and V and herein.

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- 3.2.1 Case outline(s). The case outline(s) shall be in accordance with 1.2.4 herein.
- 3.2.2 Terminal connections. The terminal connections shall be as specified on figure 1.
- 3.2.3 Truth table. The truth table shall be as specified on figure 2.
- 3.2.4 Logic diagram. The logic diagram shall be as specified on figure 3.
- 3.2.5 Waveforms and load circuit. The waveforms and load circuit shall be as specified on figure 4.
- 3.3 Electrical performance characteristics and postirradiation parameter limits. Unless otherwise specified herein, the electrical performance characteristics and postirradiation parameter limits are as specified in table I and shall apply over the full case operating temperature range.
- 3.4 Electrical test requirements. The electrical test requirements shall be the subgroups specified in table IIA. The electrical tests for each subgroup are defined in table I.
- 3.5 Marking. The part shall be marked with the PIN listed in 1.2 herein. Marking for device class M shall be in accordance with MIL-STD-883 (see 3.1 herein). In addition, the manufacturer's PIN may also be marked as listed in MIL-BUL-103. Marking for device classes B and S shall be in accordance with MIL-M-38510. Marking for device classes Q and V shall be in accordance with MIL-I-38535.
- 3.5.1 Certification/compliance mark. The compliance mark for device class M shall be a "C" as required in MIL-STD-883 (see 3.1 herein). The certification mark for device classes B and S shall be a "J" or "JAN" as required in MIL-M-38510. The certification mark for device classes Q and V shall be a "QML" as required in MIL-I-38535.
- 3.6 Certificate of compliance. For device class M, a certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-BUL-103 (see 6.7.3 herein). For device classes Q and V, a certificate of compliance shall be required from a QML-38535 listed manufacturer in order to supply to the requirements of this drawing (see 6.7.2 herein). The certificate of compliance submitted to DESC-ECS prior to listing as an approved source of supply for this drawing shall affirm that the manufacturer's product meets, for device class M the requirements of MIL-STD-883 (see 3.1 herein), or for device classes Q and V, the requirements of MIL-I-38535 and the requirements herein.
- 3.7 Certificate of conformance. A certificate of conformance as required for device class M in MIL-STD-883 (see 3.1 herein) or device classes B and S in MIL-M-38510 or for device classes Q and V in MIL-I-38535 shall be provided with each lot of microcircuits delivered to this drawing.
- 3.8 Notification of change for device class M. For device class M, notification to DESC-ECS of change of product (see 6.2 herein) involving devices acquired to this drawing is required for any change as defined in MIL-STD-420.
- 3.9 Verification and review for device class M. For device class M, DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.
- 3.10 Microcircuit group assignment for device classes M, B, and S. Device classes M, B, and S devices covered by this drawing shall be in microcircuit group number 56 (see MIL-M-38510, appendix E).
- 3.11 Serialization for device class S. All device class S devices shall be serialized in accordance with MIL-M-38510.

STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A	5962-91652	
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TABLE I. Electrical performance characteristics.

Test	Symbol	Conditions -55°C ≤ T _a ≤ +125°C unless otherwise specified	Group A subgroups	Limits		Unit
				Min	Max	
Supply current	I _{EEA} ⁺ I _{EED}	V _{EEA} , V _{EED} = -5.5 V 1/	1,3	-195		mA
			2	-145		
Reference input capacitance 2/	C _{REF}	T _C = +25°C, see 4.4.1 b	4		15	pF
Digital input capacitance 2/	C _I	T _C = +25°C, see 4.4.1 b	4		15	
Output capacitance 2/	C _O	V _{OUT+} = +2.0 V, V _{OUT-} = -2.0 V, T _A = +25°C f = 1 MHz, see 4.4.1 b	4		45	
Digital input current, logic LOW	I _{IL}	V _{EED} = -5.5 V V _I = -1.85 V	1,2,3	-10	250	μA
Digital input current, logic HIGH	I _{IH}	V _{EED} = -5.5 V V _I = -0.8 V	1,2,3	-10	250	
CONV input current	I _{IC}	V _{EED} = -5.5 V -1.85 V ≤ V _I ≤ -0.8 V	1,2,3		50	
Output resistance 2/	R _O	V _{OUT+} = +2.0 V, V _{OUT-} = -2.0 V	1,2,3	12		kΩ
Output compliance voltage 2/	V _{OC}	V _{OUT+} = +2.0 V, V _{OUT-} = -2.0 V	1,2,3	-1.2	1.2	V
Full-scale output current	I _O	V _{OUT+} = +2.0 V, V _{OUT-} = -2.0 V	1,2,3	40		mA

See footnotes at the end of table.

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TABLE 1. Electrical performance characteristics - Continued.

Test	Symbol	Conditions -55°C ≤ T _C ≤ +125°C unless otherwise specified	Group A subgroups	Limits		Unit
				Min	Max	
Maximum clock rate 3/ 4/	f _S	V _{EEA} , V _{EED} = -4.9 V, FT = 0.8 V see figure 4	4,5,6	50		MSPS
Clock to output delay 2/ 4/	t _{DC}	V _{EEA} , V _{EED} = -4.9 V, FT = 0.8 V see figure 4	9,10,11		20	ns
Data to output delay 2/ 5/	t _{DD}	V _{EEA} , V _{EED} = -4.9 V, FT = 2.0 V see figure 4	9,10,11		25	
FT to output delay 2/	t _{DF}	V _{EEA} , V _{EED} = -4.9 V, see figure 4	9,10,11		30	
Output risetime 2/ 4/	t _R	90% to 10% of FSR, FT = 0.8 V	9,10,11		4	
Output falltime 2/ 4/	t _F	10% to 90% of FSR, FT = 0.8 V	9,10,11		4	
Output voltage settling time 2/	t _{SET}	FT = 0.8 V, worst case full-scale voltage transition on OUT- to ±0.188% of FS (3/4 LSB) see figure 4	9,10,11		35	
Linearity error, differential 6/ (device type 01 only)	E _{LD}	V _{EEA} , V _{EED} = -5.2 V, I _{REF} = 0.625 mA	4,5,6	-0.048	+0.048	%
Linearity error, 6/ integral terminal based (device types 01 and 02)	E _{LI}	V _{EEA} , V _{EED} = -5.2 V, I _{REF} = 0.625 mA	4,5,6	-0.048	+0.048	%

See footnotes at the end of table.

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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions -55°C ≤ T _C ≤ +125°C unless otherwise specified	Group A subgroups	Limits		Unit
				Min	Max	
Linearity error, differential δ / (device type 02 only)	E _{LD}	V _{EEA} , V _{EED} = -5.2 V, I _{REF} = 0.625 mA	4,5,6	-0.024	+0.024	%
Absolute gain error	E _G	V _{EEA} , V _{EED} , V _{REF} = -5.2 V,	1,2,3	-5	+5	%
Output offset current	I _{OF}	V _{EEA} , V _{EED} = -4.9 V D ₁₋₁₂ = 0.8 V	1,2,3	-5	+5	μA
REF+ to REF- offset	V _{OS}	V _{EEA} , V _{EED} = -5.5 V	1,2,3	-10	+10	mV
REF- input bias current 2/	I _B	V _{EEA} , V _{EED} = -5.5 V	1,2,3		10	μA
Power supply rejection ratio 2/	PSRR	V _{EEA} , V _{EED} = -5.2 V, V _{EEA} and V _{EED} ripple = 0.6 Vp-p, F = 120 Hz I _{REF} = 0.625 mA, dB relative to 0.6 Vp-p ripple input	4,5,6		-48	dB
Power supply sensitivity	PSS	V _{EEA} , V _{EED} = ±4% of -5.2 V I _{REF} = 0.625 mA	4,5,6		-140	μA/V
Peak glitch area 7/ 2/	G _A		4,5,6		45	pV- sec

- 1/ Worst case over all data and control states.
- 2/ Guaranteed if not tested to the limits specified.
- 3/ F_s is limited only by t_{PWL}, t_{PWH}, t_S, and t_H requirements.
- 4/ Clocked mode.
- 5/ Feedthrough mode.
- 6/ OUT- connected to A_{GND}; OUT+ driving virtual ground.
- 7/ Worst case 1 LSB transition

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Device types	01 and 02	
Case outlines	J	3
Terminal number	Terminal symbol	
1	D ₉	V _{EEA}
2	D ₁₀	REF+
3	D ₁₁	REF+
4	D ₁₂ (LSB)	COMP
5	A _{GND}	V _{EED}
6	OUT+	D ₇
7	OUT-	D ₈
8	D _{GND}	D ₉
9	D ₆	D ₁₀
10	D ₅	D ₁₁ (LSB)
11	D ₄	D ₁₂ (LSB)
12	D ₃	NC
13	D ₂	A _{GND}
14	D ₁ (MSB)	OUT+
15	CONV	OUT-
16	CONV	NC
17	FT	D _{GND}
18	V _{EEA}	NC
19	REF-	D ₆
20	REF+	D ₅
21	COMP	D ₄
22	V _{EED}	D ₃
23	D ₇	D ₂ (MSB)
24	D ₈	D ₁ (MSB)
25	- - -	NC
26	- - -	CONV
27	- - -	CONV
28	- - -	FT

FIGURE 1. Terminal connections.

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FIGURE 2
TRUTH TABLE

INPUT CODING TABLE

Input Data (D ₁₋₁₂) MSB LSB	OUT+ (mA)	V _{OUT+} (mV)	OUT-(mA)	V _{OUT-} (mV)
0000 0000 0000	0.000	0.00	40.000	-1000.00
0000 0000 0001	0.009	-0.24	39.990	-999.75
0000 0000 0010	0.019	-0.49	39.980	-999.52
•	•	•	•	•
•	•	•	•	•
•	•	•	•	•
0111 1111 1111	19.995	-499.88	20.005	-500.12
1000 0000 0000	20.005	-500.12	19.995	-499.88
•	•	•	•	•
•	•	•	•	•
•	•	•	•	•
1111 1111 1101	39.980	-999.52	0.019	-0.49
1111 1111 1110	39.990	-999.75	0.009	-0.24
1111 1111 1111	40.000	-1000.00	0.000	0.00

NOTE: I_{REF} = 625 μ A, R_{LOAD} = 25 Ω

FIGURE 2. Truth table.

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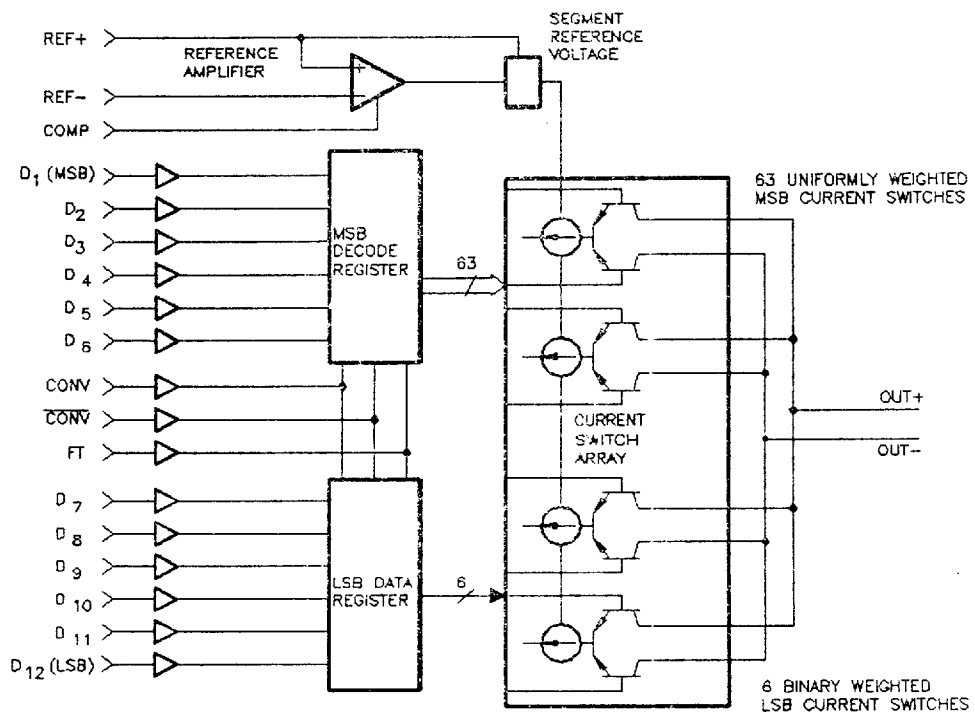


FIGURE 3. Logic diagram.

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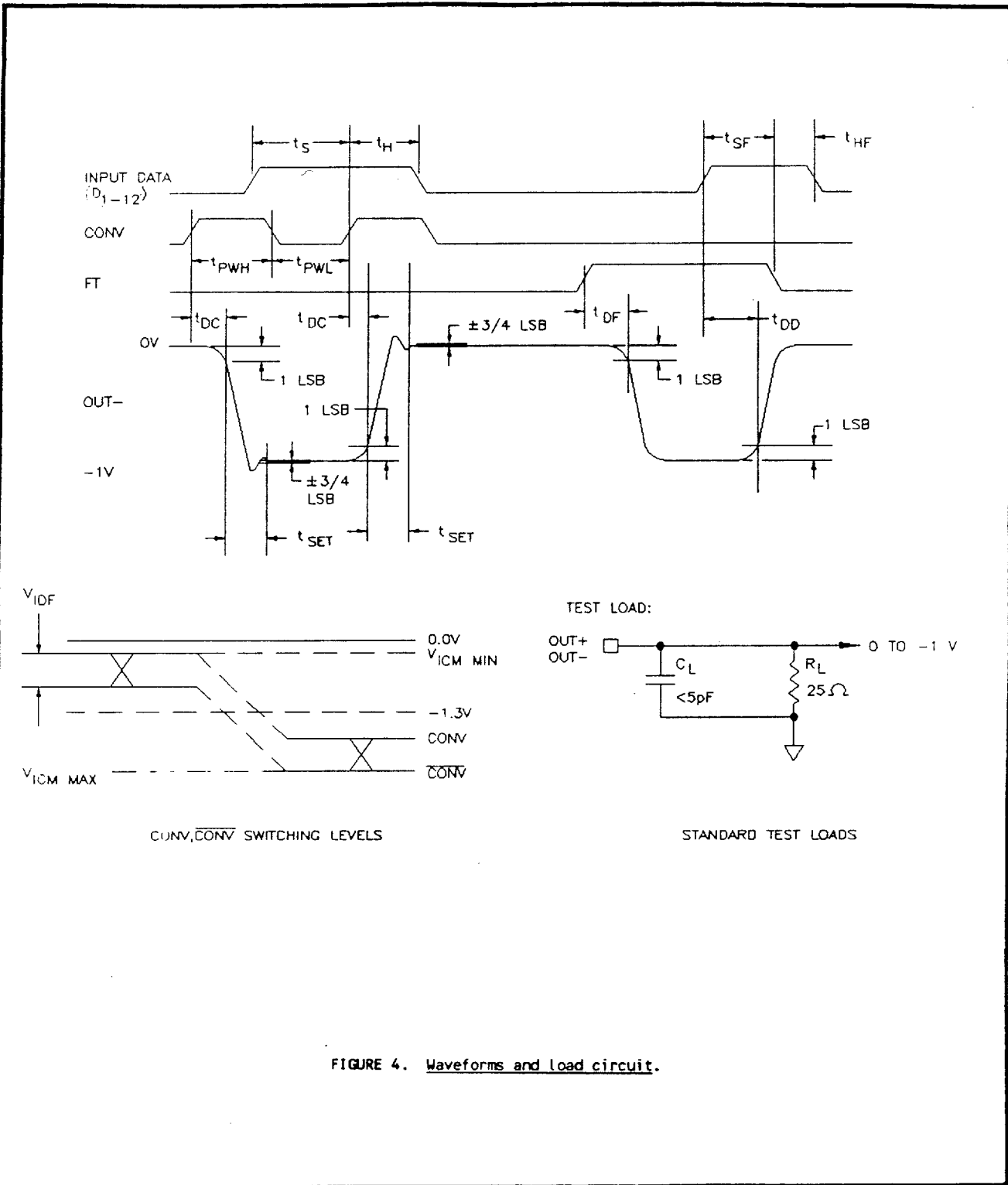


FIGURE 4. Waveforms and load circuit.

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4. QUALITY ASSURANCE PROVISIONS

4.1 Sampling and inspection. For device class M, sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein). For device classes B and S, sampling and inspection procedures shall be in accordance with MIL-M-38510 and method 5005 of MIL-STD-883, except as modified herein. For device classes Q and V, sampling and inspection procedures shall be in accordance with MIL-I-38535 and the device manufacturer's QM plan.

4.2 Screening. For device class M, screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. For device classes B and S, screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to qualification and quality conformance inspection. For device classes Q and V, screening shall be in accordance with MIL-I-38535, and shall be conducted on all devices prior to qualification and technology conformance inspection.

4.2.1 Additional criteria for device classes M, B, and S.

a. Burn-in test, method 1015 of MIL-STD-883.

(1) Test condition A, B, C, or D. For device class M, the test circuit shall be submitted to DESC-ECS for review with the certificate of compliance. For device classes B and S, the test circuit shall be submitted to the qualifying activity.

(2) $T_A = +125^\circ\text{C}$, minimum.

b. Interim and final electrical test parameters shall be as specified in table IIA herein.

4.2.2 Additional criteria for device classes Q and V.

a. The burn-in test duration, test condition and test temperature or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-I-38535. The burn-in test circuit shall be submitted to DESC-ECS with the certificate of compliance and shall be under the control of the device manufacturer's Technology Review Board (TRB) in accordance with MIL-I-38535.

b. Interim and final electrical test parameters shall be as specified in table IIA herein.

c. Additional screening for device class V beyond the requirements of device class Q shall be as specified in appendix B of MIL-I-38535 and as detailed in table IIB herein.

4.3 Qualification inspection.

4.3.1 Qualification inspection for device classes B and S. Qualification inspection for device classes B and S shall be in accordance with MIL-M-38510. Inspections to be performed shall be those specified in method 5005 of MIL-STD-883 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.5).

4.3.2 Qualification inspection for device classes Q and V. Qualification inspection for device classes Q and V shall be in accordance with MIL-I-38535. Inspections to be performed shall be those specified in MIL-I-38535 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.5).

4.4 Conformance inspection. Quality conformance inspection for device class M shall be in accordance with MIL-STD-883 (see 3.1 herein) and as specified herein. Quality conformance inspection for device classes B and S shall be in accordance with MIL-M-38510 and as specified herein. Inspections to be performed for device classes M, B, and S shall be those specified in method 5005 of MIL-STD-883 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.5). Technology conformance inspection for classes Q and V shall be in accordance with MIL-I-38535 including groups A, B, C, D, and E inspections and as specified herein except where option 2 of MIL-I-38535 permits alternate in-line control testing.

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TABLE IIA. Electrical test requirements.

Test requirements	Subgroups (per method 5005, table I)			Subgroups (per MIL-I-38535, table III)	
	Device class M	Device class B	Device class S	Device class Q	Device class V
Interim electrical parameters (see 4.2)	1,2,3	1,2,3	1,2,3	1,2,3	1,2,3
Final electrical parameters (see 4.2)	1/ ^{1/} 2/ 1,2,3, 4,5,6, 9,10,11	1/ ^{1/} 1,2,3, 4,5,6, 9,10,11	1/ ^{1/} 1,2,3, 4,5,6, 9,10,11	1/ ^{1/} 1,2,3, 4,5,6, 9,10,11	1/ ^{1/} 1,2,3, 4,5,6, 9,10,11
Group A test requirements(see 4.4)	1,2,3,2/ 4,5,6, 9,10,11	1,2,3, 4,5,6, 9,10,11	1,2,3, 4,5,6, 9,10,11	1,2,3, 4,5,6, 9,10,11	1,2,3, 4,5,6, 9,10,11
Group B end-point electrical parameters (see 4.4)	- - -	- - -	1,2,3, 4,5,6, 9,10,11	- - -	1,2,3, 4,5,6, 9,10,11
Group C end-point electrical parameters (see 4.4)	1,2,3	3/ 1,2,3	- - -	1,2,3	- - -
Group D end-point electrical parameters (see 4.4)	1,2,3	1,2,3	1,2,3	1,2,3	1,2,3
Group E end-point electrical parameters (see 4.4)	1,4	1,4	1,4	1,4	1,4

1/ PDA applies to subgroup 1.

2/ Subgroups 9, 10, and 11 are guaranteed if not tested to the limits specified in table I.

3/ Delta limits in accordance with table IIc shall be computed with reference to the previous electrical parameters.

4.4.1 Group A inspection.

- a. Tests shall be as specified in table IIA herein.
- b. Subgroup 4 (C_{REF} , C_I and C_O) shall be measured only for the initial test and after process or design changes which may affect capacitance.

4.4.2 Group B inspection. The group B inspection end-point electrical parameters shall be as specified in table IIA herein.

4.4.3 Group C inspection. The group C inspection end-point electrical parameters shall be as specified in table IIA herein.

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TABLE IIB. Additional screening for device class V.

Test	MIL-STD-883, test method	Lot requirement
Particle impact noise detection	2020	100%
Internal visual	2010, condition A or approved alternate	100%
Nondestructive bond pull	2023 or approved alternate	100%
Reverse bias burn-in	1015	100%
Burn-in	1015, total of 240 hours at +125°C	100%
Radiographic	2012	100%

TABLE IIC. Delta limits at +25°C.

Parameters 1/	Device type
	All
I_{EEA}^+ I_{EED}	±10 percent of specified value in table I.
E_{LD}	±10 percent of specified value in table I.
E_{LI}	±10 percent of specified value in table I.

1/ The above parameters shall be recorded before and after the required burn-in and life tests to determine the delta.

4.4.3.1 Additional criteria for device classes M, B, and S. Steady-state life test conditions, method 1005 of MIL-STD-883:

- a. Test condition A, B, C, or D. For device class M, the test circuit shall be submitted to DESC-ECS for review with the certificate of compliance. For device classes B and S, the test circuit shall be submitted to the qualifying activity.
- b. $T_A = +125^\circ\text{C}$, minimum.
- c. Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

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4.4.3.2 Additional criteria for device classes Q and V. The steady-state life test duration, test condition and test temperature or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-I-38535. The steady-state life test circuit shall be submitted to DESC-ECS with the certificate of compliance and shall be under the control of the device manufacturer's TRB in accordance with MIL-I-38535.

4.4.4 Group D inspection. The group D inspection end-point electrical parameters shall be as specified in table IIA herein.

4.4.5 Group E inspection. Group E inspection is required only for parts intended to be marked as radiation hardness assured (see 3.5 herein). RHA levels for device classes B, S, Q, and V shall be M, D, R, and H and for device class M shall be M and D. RHA quality conformance inspection sample tests shall be performed at the RHA level specified in the acquisition document.

- a. RHA tests for device classes B and S for levels M, D, R, and H or for device class M for levels M and D shall be performed through each level to determine at what levels the devices meet the RHA requirements. These RHA tests shall be performed for initial qualification and after design or process changes which may affect the RHA performance of the device.
- b. End-point electrical parameters shall be as specified in table IIA herein.
- c. Prior to total dose irradiation, each selected sample shall be assembled in its qualified package. It shall pass the specified group A electrical parameters in table I for subgroups specified in table IIA herein.
- d. For device classes M, B, and S, the devices shall be subjected to radiation hardness assured tests as specified in MIL-M-38510 for RHA level being tested, and meet the postirradiation end-point electrical parameter limits as defined in table I at $T_A = +25^\circ\text{C} \pm 5$ percent, after exposure.
- e. Prior to and during total dose irradiation testing, the devices shall be biased to establish a worst case condition as specified in the radiation exposure circuit.
- f. For device classes M, B, and S, subgroups 1 and 2 in table V, method 5005 of MIL-STD-883 shall be tested as appropriate for device construction.
- g. When specified in the purchase order or contract, a copy of the RHA delta limits shall be supplied.

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-M-38510 for device classes M, B, and S and MIL-I-38535 for device classes Q and V.

6. NOTES

6.1 Intended use. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.

6.1.1 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.

6.1.2 Substitutability. Device classes B and Q devices will replace device class M devices.

6.2 Configuration control of SMD's. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished in accordance with MIL-STD-481 using DD Form 1693, Engineering Change Proposal (Short Form).

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6.3 Record of users. Military and industrial users shall inform Defense Electronics Supply Center when a system application requires configuration control and which SMD's are applicable to that system. DESC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DESC-ECS, telephone (513) 296-6022.

6.4 Comments. Comments on this drawing should be directed to DESC-ECS, Dayton, Ohio 45444, or telephone (513) 296-5375.

6.5 Symbols, definitions, and functional descriptions.

6.6 One part - one part number system. The one part - one part number system described below has been developed to allow for transitions between identical generic devices covered by the four major microcircuit requirements documents (MIL-M-38510, MIL-H-38534, MIL-I-38535, and 1.2.1 of MIL-STD-883) without the necessity for the generation of unique PIN's. The four military requirements documents represent different class levels, and previously when a device manufacturer upgraded military product from one class level to another, the benefits of the upgraded product were unavailable to the Original Equipment Manufacturer (OEM), that was contractually locked into the original unique PIN. By establishing a one part number system covering all four documents, the OEM can acquire to the highest class level available for a given generic device to meet system needs without modifying the original contract parts selection criteria.

<u>Military documentation format</u>	<u>Example PIN under new system</u>	<u>Manufacturing source listing</u>	<u>Document listing</u>
New MIL-M-38510 Military Detail Specifications (in the SMD format)	5962-XXXXXZZ(B or S)YY	QPL-38510 (Part 1 or 2)	MIL-BUL-103
New MIL-H-38534 Standardized Military Drawings	5962-XXXXXZZ(H or K)YY	QML-38534	MIL-BUL-103
New MIL-I-38535 Standardized Military Drawings	5962-XXXXXZZ(Q or V)YY	QML-38535	MIL-BUL-103
New 1.2.1 of MIL-STD-883 Standardized Military Drawings	5962-XXXXXZZ(M)YY	MIL-BUL-103	MIL-BUL-103

6.7 Sources of supply.

6.7.1 Sources of supply for device classes B and S. Sources of supply for device classes B and S are listed in QPL-38510.

6.7.2 Sources of supply for device classes Q and V. Sources of supply for device classes Q and V are listed in QML-38535. The vendors listed in QML-38535 have submitted a certificate of compliance (see 3.6 herein) to DESC-ECS and have agreed to this drawing.

6.7.3 Approved sources of supply for device class M. Approved sources of supply for class M are listed in MIL-BUL-103. The vendors listed in MIL-BUL-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DESC-ECS.

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